

Bandwidth Enhancement of T-Slot Loaded Proximity Coupled Equilateral Triangular Microstrip Antenna for Multiband Operation



Engineering

KEYWORDS : Proximity coupled, Equilateral Triangular, Bandwidth, Radiation Patterns and Gain.

Mahesh C P

Research Scholar, Dept. of Applied Electronics, Gulbarga University, Gulbarga, Karnataka, INDIA

P M Hadalgi

Professor, Dept. of Applied Electronics, Gulbarga University, Gulbarga, Karnataka, INDIA.

ABSTRACT

In this paper, a compact size proximity coupled equilateral triangular microstrip antenna is designed, analyzed and fabricated. The bandwidth enhancement of microstrip antenna is done by cutting T-slot on radiating patch of equilateral triangular. The characteristics of the antenna are obtained in terms of bandwidth, gain and return loss, these properties are compared with the conventional microstrip antenna. It is shown that by choosing suitable slot dimension and location of the slot, the impedance bandwidth can be improved up to 22.03% as compared to conventional antenna with a bandwidth of 6.97%. This antenna may find its applications in WIFI IEEE 802.11, IMT (International Mobile Communication) and in radar systems. The results are presented and discussed.

INTRODUCTION

The rapid development of wireless communication technology has increased the demand for compact microstrip antennas with high gain and wideband operating frequencies. A microstrip antenna in its simplest form consists of a radiating patch on one side of a dielectric substrate and a ground plane on the other side. However, other shapes, such as the circular, square, triangular, semicircular, rectangular shapes are also used. Microstrip patch antennas are popular because of their low cost, low profile, light weight and simple fabrication process. However, the general microstrip patch antennas have some disadvantages such as lower gain and narrow bandwidth [1, 2, 3]. There are so many well-known methods to increase the bandwidth of antennas, including increase of the substrate thickness, the use of a low cost dielectric substrate, slot loaded patch antennas, pin shorted and the use of feeding techniques [4-10].

In the present work we have successfully design and developed a new T-shape slot loaded on radiating patch antenna for enhancing the bandwidth. By selecting the suitable slot shape, choosing a proper feed and setting their dimensions, a higher operating bandwidth is obtained. The summary of the obtained results showed that the bandwidth has achieved a good match.

ANTENNA DESIGN AND CONSIDERATION

The low cost glass epoxy substrate material of thickness $h = 0.32$ cm and dielectric constant $\epsilon_r = 4.2$ is used to fabricate the design antenna. The proposed antenna is made by using computer software AUTOCAD to gain better accuracy. The photolithography process is used to fabricate the antenna.

signed for the resonant frequency of 3 GHz using the equations present in the literature for the design of equilateral triangular microstrip antenna. The equilateral triangular microstrip patch antenna is made up of equal side length 'a' cm over a substrate S_1 with thickness 'h' cm. The value of 'a' is calculated by the equation (1).

$$a = \frac{2C}{3f_r \sqrt{\epsilon_r}} \quad (1)$$

The L_f and W_f are the length and width of the microstripline feed on the top surface of substrate S_2 , which is used to excite the patch. The substrate S_2 is placed below the substrate S_1 such that the tip of the feedline and the center of the radiating patch coincide one over the other. The bottom surface of the substrate acts as the ground plane.

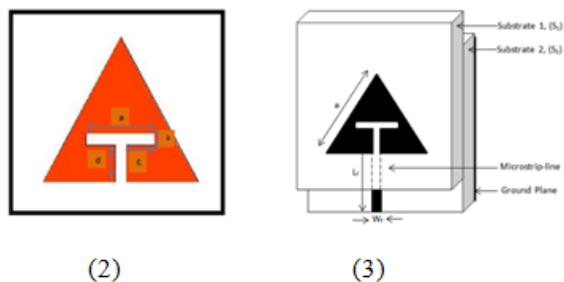


Figure 2, 3: Top view and Geometry of TSPCETMSA

The Fig. 2 and Fig. 3 show the top view and geometry of T-slot loaded proximity coupled equilateral triangular microstrip antenna (TSPCETMSA) respectively, in which the proposed antenna is modified by employing cross slot on the radiating patch, where a, b, c and d are the dimensions of the slot, which is shown in Fig. 2. All the specifications of the designed antenna are given in Table. 1.

TABLE - 1 DESIGNPARAMETERSOF PCETMSA AND TSPCETMSA

Antenna Parameters	Dimensions in cm
Side length of equilateral triangle (a)	2.70
Length of the feedline L_f	2.5
Width of the feedline W_f	0.633
Length and width of the ground plane (L_g and W_g)	4.6

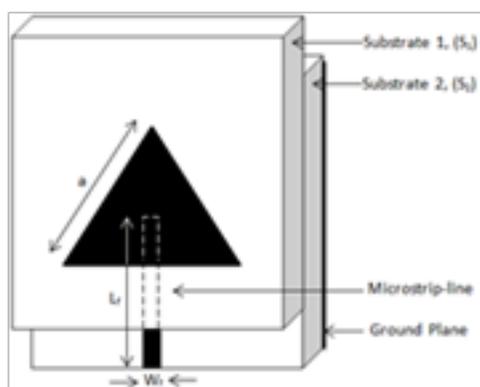


Figure 1: Geometry of PCETMSA

The Fig. 1 shows top view geometry of proximity coupled equilateral triangular microstrip antenna (PCETMSA), which is de-

Thickness of substrate S_1 and S_2 (h1+h2)	0.64
a	1.2
b	0.2
c	0.5
d	0.6

EXPERIMENTAL RESULTS AND DISCUSSION

The Vector Network Analyzer (Rohde & Schwarz, German make ZVK Model No. 1127.8651) is used to measure the experimental return loss versus frequency of PCETMSA and CSPCETMSA.

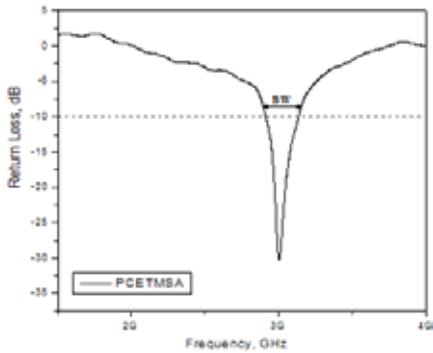


Figure 4: Variation of Return Loss v/s Frequency of PCETMSA

The Fig. 4 shows the variation of return loss versus frequency of PCETMSA. From this figure, it is found that, the PCETMSA resonates at 3 GHz of frequency which is equivalent to the designed frequency of 3 GHz. The experimental impedance bandwidth over return loss than -10dB is calculated using the formula,

$$BW = \left[\frac{f_2 - f_1}{f_c} \right] \times 100\% \quad (2)$$

where, f_2 and f_1 are the upper and lower cut of points of resonating frequency when its return loss reaches -10 dB. The impedance bandwidth of PCETMSA is found to be 6.97%.

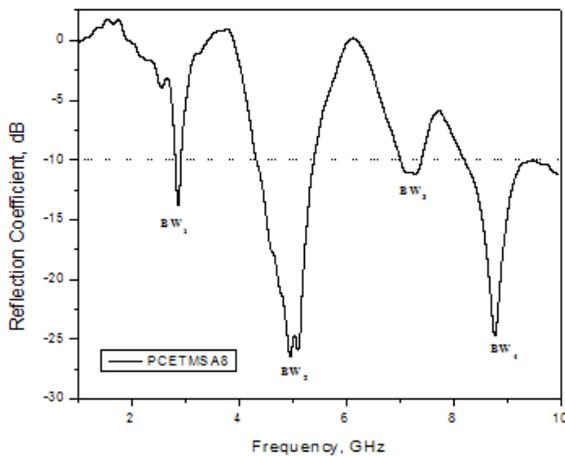


Figure 5: Variation of Return Loss v/s Frequency of TSPCETMSA

The results obtained by interpreting Fig. 5 indicate that the variation of return loss versus frequency of TSPCETMSA, resonates at four modes of frequencies $f_1, f_2, f_3,$ and f_4 with their respective impedance bandwidths $BW_1 = 4.53\%$ (2.80-2.93 GHz), $BW_2 = 22.03\%$ (4.32-5.39 GHz), $BW_3 = 5.56\%$ (6.99-7.39 GHz) and $BW_4 = 19.90\%$ (8.19-10.00 GHz). The minimum return loss and VSWR measured are shown in Table. 2.

TABLE - 2 MEASURED MIN. RETURN LOSS AND VSWR

Antennas	Freq. in GHz.	Min. Return loss in dB.	VSWR
PCETMSA	3.00	-30.26	1.12
TSPCETMSA	2.85	-13.57	1.76
	4.95	-26.74	1.76
	7.20	-11.10	1.80
	8.77	-24.87	1.82

The X-Y plane co-polar and cross-polar radiation patterns of PCETMSA and TSPCETMSA are measured at their resonating frequencies and are shown in Fig.6 to Fig.10. These figures indicate that the antennas show broad side radiation characteristics. Further, the calculated HPBW is given in Table. 3.

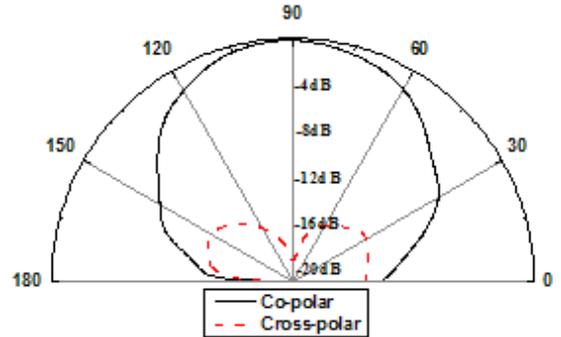


Figure 6: Radiation pattern PCETMSA at 3 GHz

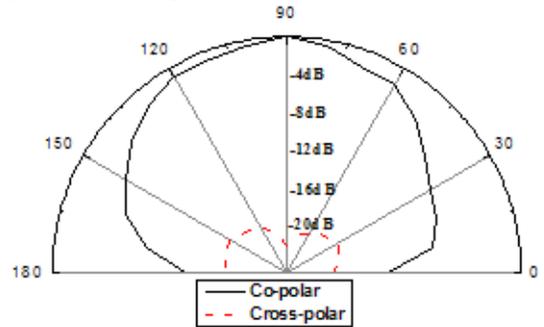


Figure 7: Radiation pattern TSPCETMSA at 2.85 GHz

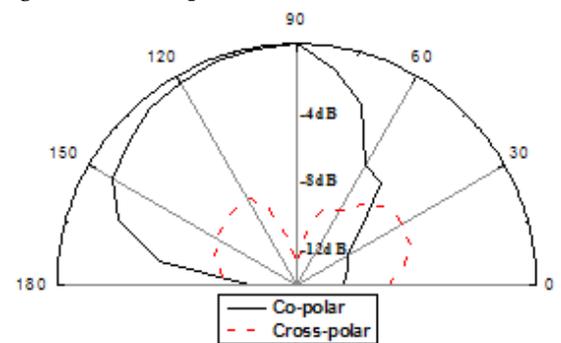


Figure 8: Radiation pattern TSPCETMSA at 4.95 GHz

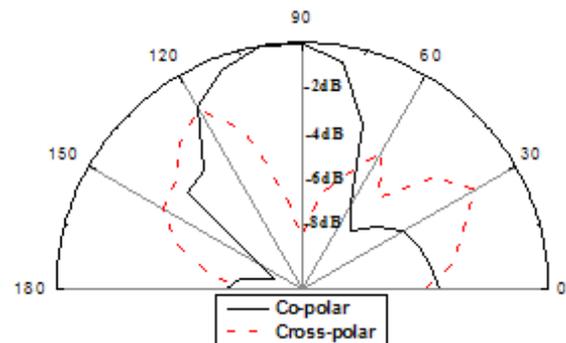


Figure 9: Radiation pattern TSPCETMSA at 7.20 GHz

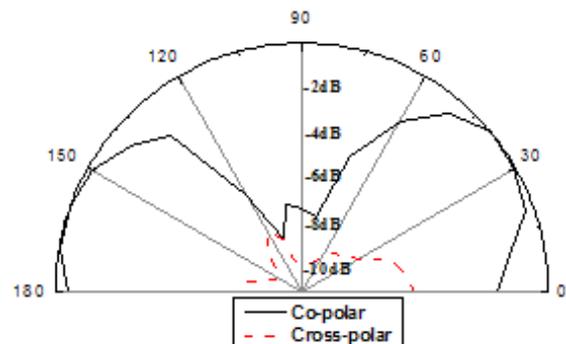


Figure 10: Radiation pattern TSPCETMSA at 8.77 GHz

The gain of proposed antenna is calculated using absolute gain method given by the equation (3),

$$G(dB) = 10 \log \left(\frac{P_r}{P_t} \right) - (G_t)dB - 20 \log \left(\frac{\lambda_0}{4\pi R} \right) dB \quad (3)$$

where, P_t and P_r are transmitted and received powers respectively, G_t is the gain of the pyramidal horn antenna and R is the distance between transmitting antenna and antenna under test. The gain of the antenna is also tabulated in Table 3.

TABLE - 3 CALCULATED HPBW AND GAIN

Antennas	Freq. in GHz.	HPBW in degrees	Gain in dB
PCETMSA	3	72°	6.38
	2.85	82°	6.85
TSPCETMSA	4.95	70°	3.21
	7.20	64°	5.08
	8.77	50°	4.00

CONCLUSIONS

From this detailed study, it is concluded that the proposed antenna is simple in its geometry and construction. The PCETMSA antenna gives a single band but after loading a T-slot on radiating patch, which resonates for quad band operating frequency points and is quite good in enhancing the impedance bandwidth and gives better gain with broadside radiation patterns at examined resonating frequencies. This antenna may find applications for WIFI IEEE 802.11, IMT (International Mobile Communication) and in radar systems.

REFERENCE

1. Thomas A. Milligan. 2nd Ed. Modern antenna design. pp. 318-354. | 2. A.K Bhattacharjee, S.R Bhadra, D.R. Pooddar and S.K. Chowdhury. 1989. Equivalence of impedance and radiation properties of square and circular microstrip patches antennas. IEE Proc. 136 (Pt. H, no. 4): 338-342. | 3. R. G. Vaughan. 1988. Two-port higher mode circular microstrip antennas. IEEE, Trans. Antennas Propagat. 36(3): 309-321. | 4. AyeshaAslam and F. A. Bhatti, "Novel inset feed design technique for Microstrip patch antenna", Proc. IEEE Vol. 978-1, pp.0215-219, 2010. | 5. Bai-wen Tian, Jin-ming, "A Design of Dual-Band H-shaped Microstrip-line-Fed printed Wide-Slot Antenna", Proc. IEEE, Vol. 978-1, pp. 201-203, 2008. | 6. Reena Rani and Dushyant Kumar, "Comparative Study of T Slot and Cross Slot Coupled Microstrip Patch Antenna", International Journal of Advanced Research in Computer Science and Software Engineering", Vol. 3, Issue. 4, April 2014. Pp. 441-445. | 7. KalyanMondal and P. K. Ray, "T Shape Dual Band Microstrip Patch Antenna with Simple Modified Ground Plane for Wireless Communications", International Journal of Advanced Electronics & Communication Systems, Vol. 3, Issue. 4, Aug-Sept-2014. | 8. Rajesh K Vishwakarma, J A Ansari and M K Meshram, "Equilateral Traingular Microstrip Antenna for Circular Polarization Dual-Band Operation", Indian Journal of Radio & Space Physics, Vol. 35, Aug-2006, pp. 293-296. | 9. SanyogRawat and K K Sharma, "Circularly Polarized Microstrip Patch Antenna with T-shaped Slot" IJECT, Vol. 4, Issue. 4, April-June 2013, pp. 65-69. | 10. RajarshiSanyal, Rajeev Kr. Singh and PoulamiMahata, "Bandwidth Enhancement of Pin Shorted Triangular Patch Antenna with Circular Notch", International Journal of Computer Applications, Vol. 63, No. 1, February 2013, pp. 15-19. |